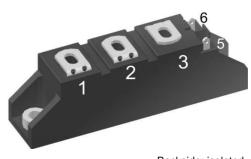
**Thyristor Module** 

### MCC26-12io8B

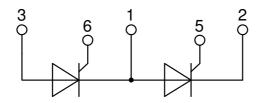
$V_{\text{RRM}}$	<i>=</i> 2x 1200 V		
I <sub>tav</sub>	=	27 A	
VT	=	1.27 V	

Phase leg

Part number MCC26-12io8B



Backside: isolated **E**72873



#### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al2O3-ceramic

#### **Applications:**

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

#### Package: TO-240AA

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

#### Terms Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office. Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office. Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

to perform joint risk and quality assessments;
the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

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Data according to IEC 60747and per semiconductor unless otherwise specified

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# LIXYS

## MCC26-12io8B

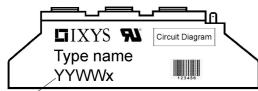
Thyristo					Ratings		!
Symbol	Definition	Conditions		min.	typ.	max.	Uni
V <sub>RSM/DSM</sub>	max. non-repetitive reverse/forwa	rd blocking voltage	$T_{vJ} = 25^{\circ}C$			1300	٧
V <sub>RRM/DRM</sub>	max. repetitive reverse/forward bl	ocking voltage	$T_{vJ} = 25^{\circ}C$			1200	٧
R/D	reverse current, drain current	V <sub>R/D</sub> = 1200 V	$T_{vJ} = 25^{\circ}C$			100	μA
		V <sub>R/D</sub> = 1200 V	$T_{vJ} = 125^{\circ}C$			3	mA
V <sub>T</sub>	forward voltage drop	$I_{T} = 40 \text{ A}$	$T_{vJ} = 25^{\circ}C$			1.27	٧
		Ι <sub>τ</sub> = 80 A				1.64	V
		$I_{T} = 40 \text{ A}$	$T_{vJ} = 125 \circ C$			1.27	٧
		I <sub>T</sub> = 80 A				1.65	V
I TAV	average forward current	$T_c = 85^{\circ}C$	$T_{vJ} = 125^{\circ}C$			27	A
T(RMS)	RMS forward current	180° sine				42	A
V <sub>T0</sub>	threshold voltage		$T_{VJ} = 125^{\circ}C$			0.85	٧
r <sub>T</sub>	slope resistance	oss calculation only				11	mΩ
R <sub>thJC</sub>	thermal resistance junction to cas	e				0.88	K/W
<b>R</b> <sub>thCH</sub>	thermal resistance case to heatsi	nk			0.20		K/W
P <sub>tot</sub>	total power dissipation		$T_c = 25^{\circ}C$			115	W
I <sub>TSM</sub>	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{vJ} = 45^{\circ}C$			520	A
		t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			560	A
		t = 10 ms; (50 Hz), sine	T <sub>vJ</sub> = 125°C			440	A
		t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			475	A
l²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{vJ} = 45^{\circ}C$			1.35	kA²s
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			1.31	kA²s
		t = 10 ms; (50 Hz), sine	T <sub>vJ</sub> = 125°C			970	A <sup>2</sup> s
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			940	A²s
CJ	junction capacitance	$V_{\rm R} = 400  \text{V}$ f = 1 MHz	$T_{VJ} = 25^{\circ}C$		22		pF
P <sub>GM</sub>	max. gate power dissipation	t <sub>P</sub> = 30 μs	T <sub>c</sub> = 125°C			10	W
		$t_{\rm P} = 300 \mu {\rm s}$				5	W
PGAV	average gate power dissipation					0.5	W
(di/dt) <sub>cr</sub>	critical rate of rise of current	T <sub>v.i</sub> = 125 °C; f = 50 Hz re	epetitive. I <sub>T</sub> = 45 A			150	A/μs
(/Ci		$t_{\rm P} = 200 \mu {\rm s}; di_{\rm G}/dt = 0.45 {\rm A}/\mu {\rm s}; -$	• • •				
			on-repet., $I_{\tau} = 27 \text{ A}$			500	A/μs
(dv/dt) <sub>cr</sub>	critical rate of rise of voltage	$V = \frac{2}{3} V_{\text{DRM}}$	$T_{y_1} = 125^{\circ}C$			1000	1
( <b></b> ) <b></b> ) cr		$R_{GK} = \infty$ ; method 1 (linear volta	••				
V <sub>gT</sub>	gate trigger voltage	$V_{\rm D} = 6 \text{ V}$	$T_{v,l} = 25^{\circ}C$			1.5	v
- 61	J 33	. u   • ·	$T_{VJ} = -40^{\circ}C$			1.6	v
I <sub>GT</sub>	gate trigger current	$V_{D} = 6 V$	$T_{\rm VJ} = 25^{\circ}\rm C$			100	mA
■GT	gate ingger our ent	v <sub>D</sub> = 0 v	$T_{VJ} = -40^{\circ}C$			200	mA
V <sub>gd</sub>	gate non-trigger voltage	$V_{D} = \frac{2}{3} V_{DBM}$	$T_{vJ} = -40^{\circ} \text{ C}$ $T_{vJ} = 125^{\circ} \text{ C}$			0.2	V
	gate non-trigger current	$\mathbf{v}_{\mathrm{D}} = 73 \mathbf{v}_{\mathrm{DRM}}$	T <sub>VJ</sub> = 125 O			10	mA
		t 10 up	$T_{y_J} = 25 ^{\circ}C$				
IL	latching current	$t_p = 10 \ \mu s$ $I_G = 0.45 \ A; \ di_G / dt = 0.45 \ A / \mu s$				450	mA
I <sub>H</sub>	holding current	$V_{D} = 6 V R_{GK} = \infty$	$T_{v_J} = 25 \degree C$			200	mA
t <sub>gd</sub>	gate controlled delay time	$V_{D} = \frac{1}{2} V_{DRM}$	$T_{vJ} = 25 ^{\circ}C$			2	μs
-		$I_{\rm G} = 0.45 \text{A};  \text{di}_{\rm G}/\text{dt} = 0.45 \text{A}/\mu\text{s}$	6				
t <sub>q</sub>	turn-off time	$V_{\rm B} = 100 \text{ V}; \ \text{I}_{\rm T} = 20 \text{ A}; \ \text{V} = \frac{2}{3}$		1	150		μs
1		$di/dt = 10 \text{ A}/\mu \text{s} dv/dt = 20 \text{ V}$					

 $\ensuremath{\mathsf{IXYS}}$  reserves the right to change limits, conditions and dimensions.

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### MCC26-12io8B

Package TO-240AA				Ratings				
Symbol	Definition	Conditions			min.	typ.	max.	Unit
	RMS current	per terminal					200	Α
T <sub>vj</sub>	virtual junction temperature				-40		125	°C
T <sub>op</sub>	operation temperature				-40		100	°C
T <sub>stg</sub>	storage temperature				-40		125	°C
Weight						81		g
M <sub>D</sub>	mounting torque				2.5		4	Nm
M <sub>T</sub>	terminal torque				2.5		4	Nm
d <sub>Spp/App</sub>	creenade distance on surfac	e l striking distance through air	terminal to terminal	13.0	9.7			mm
<b>d</b> <sub>Spb/Apb</sub>	creepage distance on surface   striking distance through air		terminal to backside	16.0	16.0			mm
V	isolation voltage t = 1 second				3600			V
		t = 1 minute	50/60 Hz, RMS; liso∟ ≤ 1 mA		3000			V



Date Code

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MCC26-12io8B	MCC26-12io8B	Box	36	457787

Similar Part	Package	Voltage class
MCMA35P1200TA	TO-240AA-1B	1200
MCMA50P1200TA	TO-240AA-1B	1200

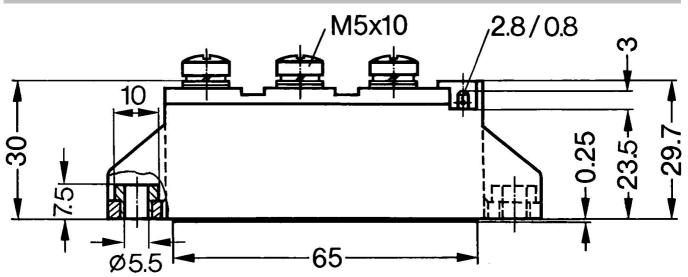
Equivalent Circuits for Simulation		* on die level	T <sub>vj</sub> = 125 °C	
	⊢R₀_⊢	Thyristor		
V <sub>0 max</sub>	threshold voltage	0.85		V
$\mathbf{R}_{0 \max}$	slope resistance *	9.8		mΩ

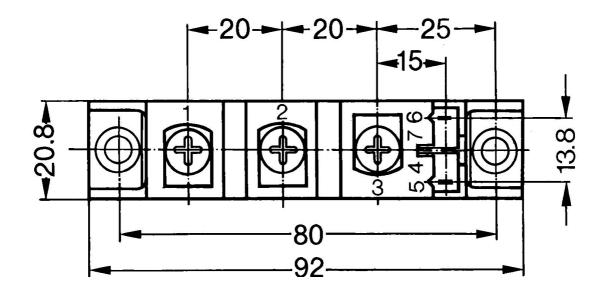
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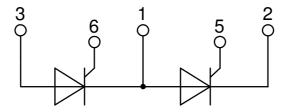
### MCC26-12io8B

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Outlines TO-240AA



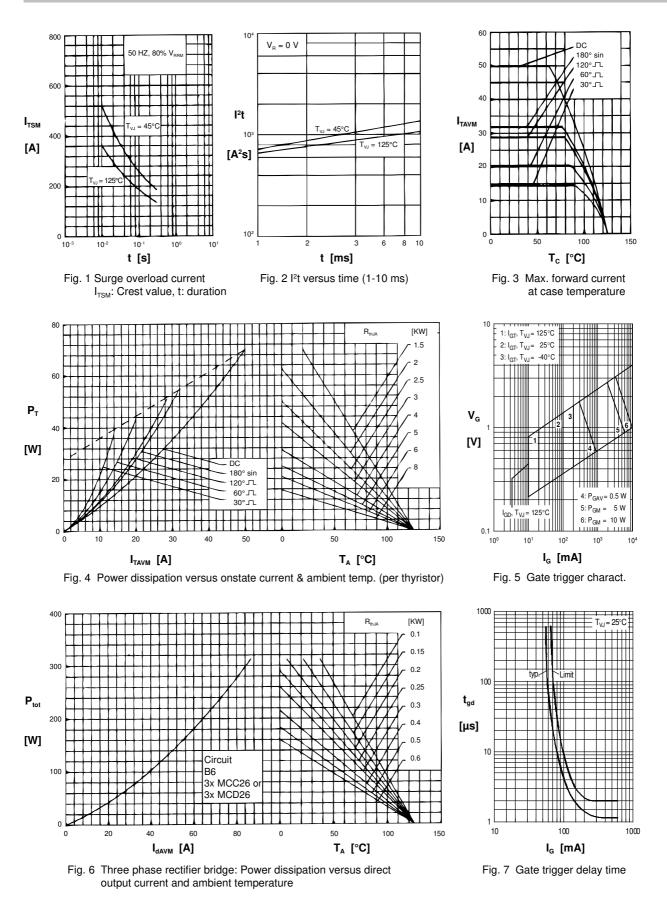




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### Thyristor

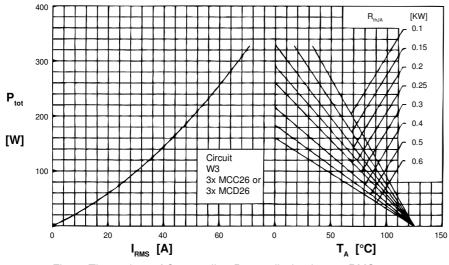


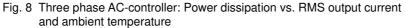
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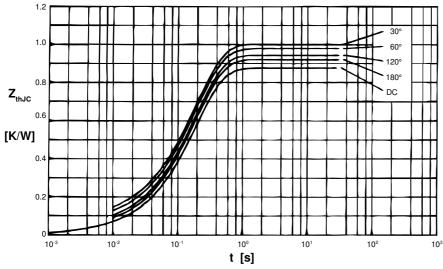
### MCC26-12io8B

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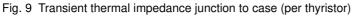
### Thyristor

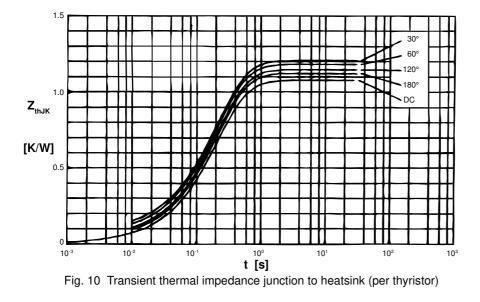






$\rm R_{\rm thJC}$ for various conduction angles d:						
	d R <sub>tt</sub>	<sub>ייזכ</sub> [K/W]				
	DC	0.88				
	180°	0.92				
	120°	0.95				
	60°	0.98				
	30°	1.01				
Con	Constants for Z <sub>thuc</sub> calculation:					
i I	R <sub>thi</sub> [K/W	] t <sub>i</sub> [s]				
1	0.019	0.0031				
2	0.029	0.0216				
3	0.832	0.1910				





R <sub>th</sub>	<sub>к</sub> for varic	us conduction angles d:
	d R <sub>th</sub>	<sub>JK</sub> [K/W]
	DC	1.08
	180°	1.12
	120°	1.15
	60°	1.18
	30°	1.21
Co	nstants fo	$r Z_{thJK}$ calculation:
i	R <sub>thi</sub> [K/W]	t <sub>i</sub> [s]
1	0.019	0.0031
2	0.029	0.0216
3	0.832	0.1910
4	0.200	0.4500

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